TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC4521BP

TC4521BP 24 – STAGE FREQUENCY DIVIDER

TC4521BP is frequency divider consisting of 24 stages of flipflop. The input section is equipped with an inverter to enable to use either RC oscillator circuit or crystal oscillator circuit and to accept pulse from external clock source.

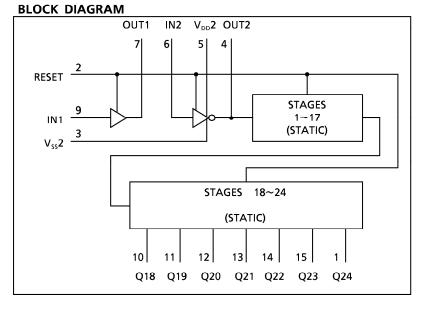
Each flip-flop is inverted by the falling edge of the output of previous stage flip-flop and this can count up to the maximum of $2^{24}=16,777,216$.

Since six outputs, 2^{18} , 2^{19} , 2^{20} , 2^{21} , 2^{22} , and 2^{23} are available besides of 2^{24} , adjustment of frequency divided output can be achieved.

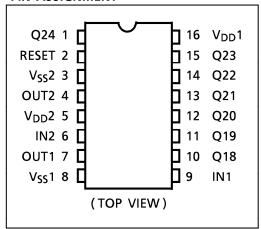
16 P (DIP16-P-300-2.54A) Weight: 1.00g (Typ.)

MAXIMUM RATINGS

| CHARACTERISTIC | SYMBOL | RATING | UNIT | |
|--------------------------------|-------------------|------------------------------------|------|--|
| DC Supply Voltage | V _{DD} 1 | $V_{SS}1 - 0.5 \sim V_{SS}1 + 20$ | v | |
| DC Supply Voltage | V _{DD} 2 | $V_{SS}1 - 0.5 \sim V_{DD}1 + 0.5$ | | |
| Input Voltage | VIN | $V_{SS}1 - 0.5 \sim V_{DD}1 + 0.5$ | < | |
| Output Voltage | V _{OUT} | $V_{SS}1 - 0.5 \sim V_{DD}1 + 0.5$ | | |
| DC Input Current | I _{IN} | ± 10 | mA | |
| Power Dissipation | P _D | 300 | mW | |
| Operating Temperature Range | T _{opr} | - 40~85 | °C | |
| Storage Temperature Range | T _{stg} | - 65~150 | °C | |



PIN ASSIGNMENT

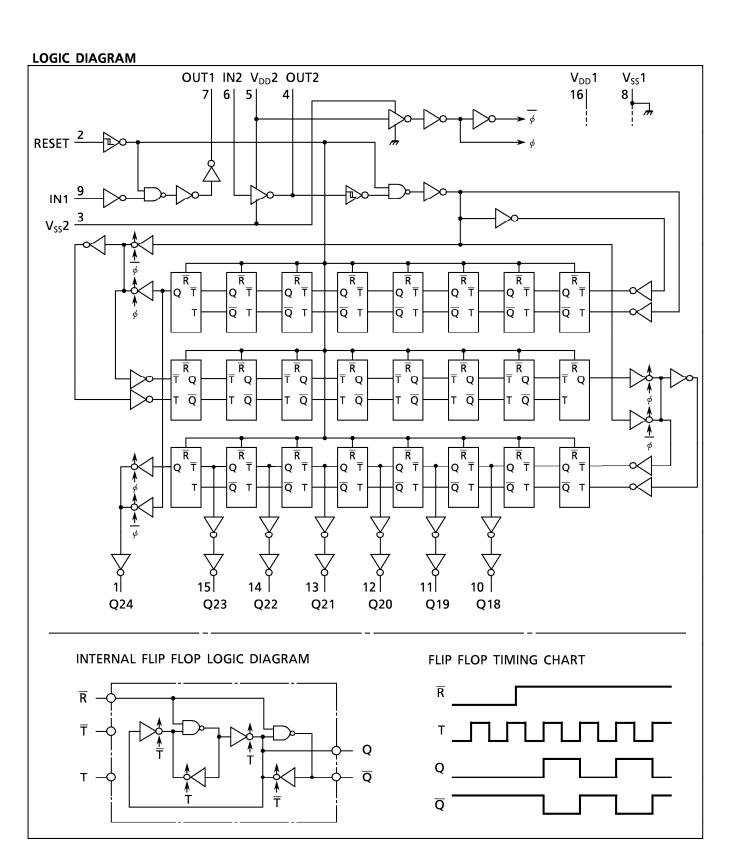


COUNT CAPACITY

| OUTPUT | COUNT CAPACITY |
|--------|---------------------------|
| Q18 | 2 ¹⁸ = 262,144 |
| Q19 | 2 ¹⁹ = 524,288 |
| Q20 | $2^{20} = 1,048,576$ |
| Q21 | $2^{21} = 2,097,152$ |
| Q22 | $2^{22} = 4,194,304$ |
| Q23 | $2^{23} = 8,388,608$ |
| Q24 | $2^{24} = 16,777,216$ |

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RECOMMENDED OPERATING CONDITIONS ($V_{SS}1 = V_{SS}2 = 0V$)

| CHARACTERISTIC | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|-------------------|--------------------|----------------|------|------|-------------------|------|
| DC Supply Voltage | $V_{DD}1, V_{DD}2$ | | 3 | _ | 18 | V |
| Input Voltage | V _{IN} | | 0 | _ | V _{DD} 1 | V |

STATIC ELECTRICAL CHARACTERISTICS ($V_{SS}1 = V_{SS}2 = 0V$, $V_{DD}1 = V_{DD}2$)

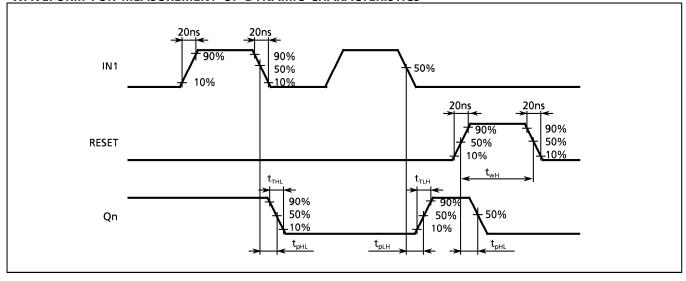
| CHARACTERISTIC SYN | | YM- TEST CONDITION | | – 40°C | | 25°C | | | 85°C | | UNIT |
|--|-----------------|---|---------------------|-----------------------------------|----------------------|-----------------------------------|---|------------------------|-----------------------------------|----------------------------|------------|
| CHARACTERISTIC | BOL | TEST CONDITION | (V) | MIN. | MAX. | MIN. | TYP. | MAX. | MIN. | MAX. | UNIT |
| High-Level Output Voltage | V _{OH} | $ I_{OUT} < 1\mu A$ $V_{IN} = V_{SS}, V_{DD}$ | 5 10 15 | 4.95 9.95 14.95 | _ _ _ | 4.95 9.95 14.95 | 5.00 10.00 15.00 | - - | 4.95 9.95 14.95 | _ _ _ | ., |
| Low-Level Output Voltage | V _{OL} | $ I_{OUT} < 1\mu A$ $V_{IN} = V_{SS}, V_{DD}$ | 5 10 15 | | 0.05 0.05 0.05 | _ _ _ | 0.00 0.00 0.00 | 0.05 0.05 0.05 | 1 1 | 0.05 0.05 0.05 | V |
| Output High Current | I _{OH} | $V_{OH} = 4.6V$ $V_{OH} = 2.5V$ $V_{OH} = 9.5V$ $V_{OH} = 13.5V$ $V_{IN} = V_{SS}, V_{DD}$ | 5 5 10 15 | - 0.61 - 2.5 - 1.5 - 4.0 | - - - | - 0.51 - 2.1 - 1.3 - 3.4 | - 1.0 - 4.0 - 2.2 - 9.0 | — — — | - 0.42 - 1.7 - 1.1 - 2.8 | - - - | - mA |
| Output Low Current | I _{OL} | $V_{OL} = 0.4V$ $V_{OL} = 0.5V$ $V_{OL} = 1.5V$ $V_{IN} = V_{SS}, V_{DD}$ | 5 10 15 | 0.61 1.5 4.0 | 1 1 1 | 0.51 1.3 3.4 | 1.2 3.2 12.0 | 1 1 1 | 0.42 1.1 2.8 | 1 1 1 | IIIA |
| Input High Voltage | V _{IH} | $V_{OUT} = 0.5V, 4.5V$ $V_{OUT} = 1.0V, 9.0V$ $V_{OUT} = 1.5V, 13.5V$ $ I_{OUT} < 1\mu A$ | 5 10 15 | 3.5 7.0 11.0 | 1 1 1 | 3.5 7.0 11.0 | 2.75 5.5 8.25 | 1 1 1 | 3.5 7.0 11.0 | 1 1 1 | V |
| Input Low Voltage | V _{IL} | $V_{OUT} = 0.5V, 4.5V$ $V_{OUT} = 1.0V, 9.0V$ $V_{OUT} = 1.5V, 13.5V$ $ I_{OUT} < 1\mu A$ | 5 10 15 | 1 1 1 | 1.5 3.0 4.0 | 1 1 | 2.25 4.5 6.75 | 1.5 3.0 4.0 | 1 1 1 | 1.5 3.0 4.0 | v |
| Input "H" Level | I _{IH} | V _{IH} = 18V | 18 | _ | 0.1 | _ | 10 ⁻⁵ | 0.1 | _ | 1.0 | |
| Current "L" Level Quiescent Supply Current | I _{IL} | $V_{IL} = 0V$ $V_{IN} = V_{SS}, V_{DD} *$ | 18 5 10 15 | 1 1 1 | 5 10 20 | - | - 10 ⁻⁵ 0.005 0.010 0.015 | - 0.1 5 10 20 | 1 1 1 | - 1.0 150 300 600 | μ Α |

^{*} All valid input combinations.

DYNAMIC ELECTRICAL CHARACTERISTICS (Ta = 25°C, $V_{SS}1 = V_{SS}2 = 0V$, $V_{DD}1 = V_{DD}2$, $C_L = 50pF$)

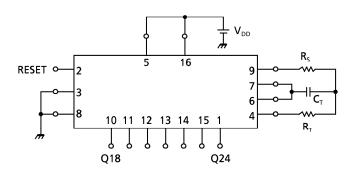
| CHARACTERISTIC | SYMBOL | TEST CONDITION | V _{DD} (V) | MIN. | TYP. | MAX. | UNIT |
|--|--------------------------------------|----------------|---------------------|------------------|---------------------|---------------------|---------|
| Output Transition Time (Low to High) | t _{TLH} | | 5 10 15 | | 70 35 30 | 200 100 80 | |
| Output Transition Time (High to Low) | t _{THL} | | 5 10 15 | _ _ _ | 70 35 30 | 200 100 80 | ns |
| Propagation Delay Time (IN2 - Q18) | t _{pLH} t _{pHL} | | 5 10 15 | _ _ _ _ | 1.1 0.5 0.3 | 9.0 3.5 2.7 | |
| Propagation Delay Time (IN2 - Q24) | t _{pLH} t _{pHL} | | 5 10 15 | _ _ _ | 1.4 0.6 0.4 | 12 4.5 3.5 | μ s |
| Propagation Delay Time (RESET - Qn) | t _{pHL} | | 5 10 15 | _ _ _ | 220 100 70 | 2600 1000 750 | ns |
| Max. Clock Frequency | f _{CL} | | 5 10 15 | 3 6 8 | 9.5 17.5 23.5 | _ _ _ | MHz |
| Max. Clock Input Rise Time Max. Clock Input Fall Time | t _{rCL} | | 5 10 15 | | No Limit | | μs |
| Min. Clock Pulse Width | t _W | | 5 10 15 | — — — | 55 25 16 | 385 150 120 | nc |
| Min. Pulse Width (RESET) | t _{WH} | | 5 10 15 | _ _ _ | 60 26 20 | 385 150 120 | ns |
| Input Capacitance | C _{IN} | | | _ | 5 | 7.5 | pF |

WAVEFORM FOR MEASUREMENT OF DYNAMIC CHARACTERISTICS



APPLICATION CIRCUIT

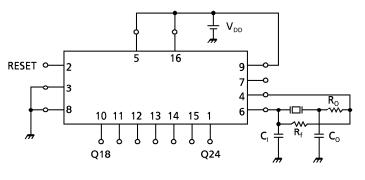
* When CR oscillation is used as time reference



$$R_S\!\ge\!2R_T$$

$$f_{\rm OSC}\!\simeq\!\frac{1}{2.2R_T~C_T}$$

* When crystal oscillation circuit is used as the time reference



Typical data

| X'tal (Hz) | C _I , C _O (pF) | R_{O} (Ω) | |
|------------|--------------------------------------|----------------------|--|
| 32.768k | 23 | 500k | |
| 100k | 60 | 100k | |
| 1M | 45~50 | 100 | |
| 4.194304M | 12~15 | 0 | |

$$R_f{=}10M\Omega$$

DIP 16PIN OUTLINE DRAWING (DIP16-P-300-2.54A)

Unit in mm

